



**Canova Tech**

*The Art of Silicon Sculpting*

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*IEEE802.3cg TF*

*PSD mask and updated EMC simulations*

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# Channel Characteristics

- Channel defined as in

[http://www.ieee802.org/3/cg/public/Sept2017/DiBiasoBergner\\_01c\\_0917.pdf](http://www.ieee802.org/3/cg/public/Sept2017/DiBiasoBergner_01c_0917.pdf) slide #18

Return Loss (f)       $> 14$  dB      for f (0.3MHz -> 10MHz)  
                          $> 14 - 10 \cdot \log_{10}(f/10)$  dB      for f (10MHz -> 40MHz)

Insertion Loss (f)  $< 1.0 + 1.6 \cdot (f-1)/9$  dB      for f (0.3MHz -> 10MHz)  
                          $< 2.6 + 2.3 \cdot (f-10)/23$  dB      for f (10MHz -> 33MHz)  
                          $< 4.9 + 2.3 \cdot (f-33)/33$  dB      for f (33MHz -> 40MHz)

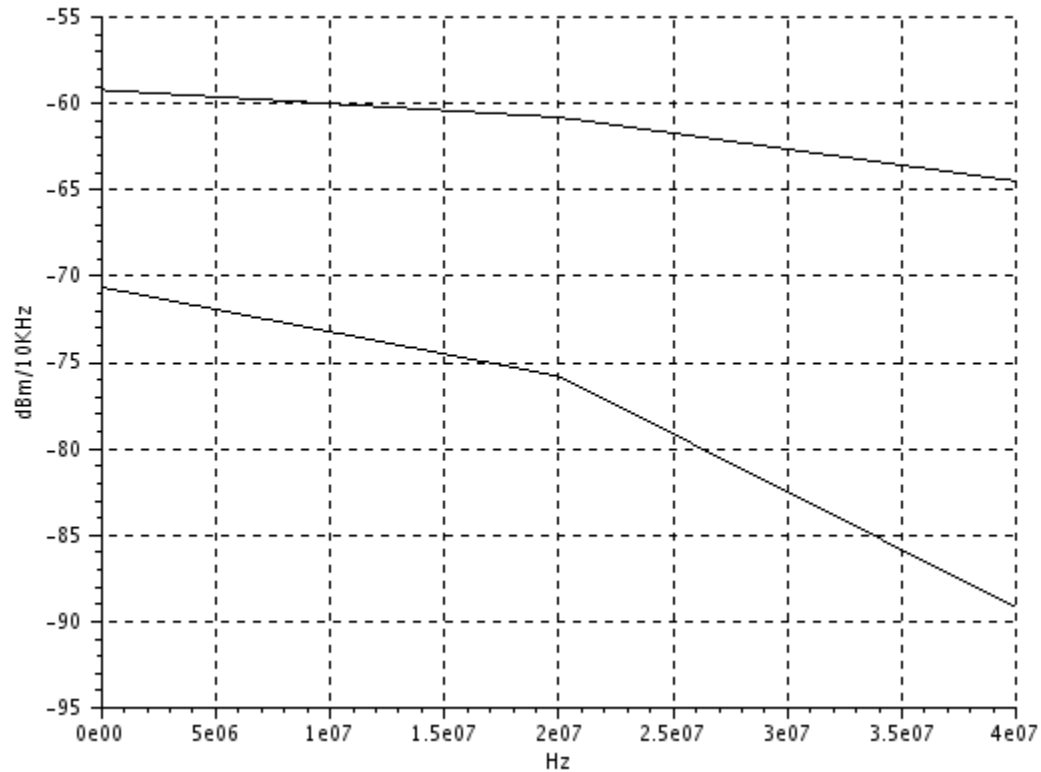
Mode Conversion Loss (f)  $> 30$  dB      for f (0.3MHz -> 20MHz)  
                          $> 30 - 20 \cdot \log_{10}(f/20)$  dB      for f (20MHz -> 200MHz)

# Proposal for PSD mask

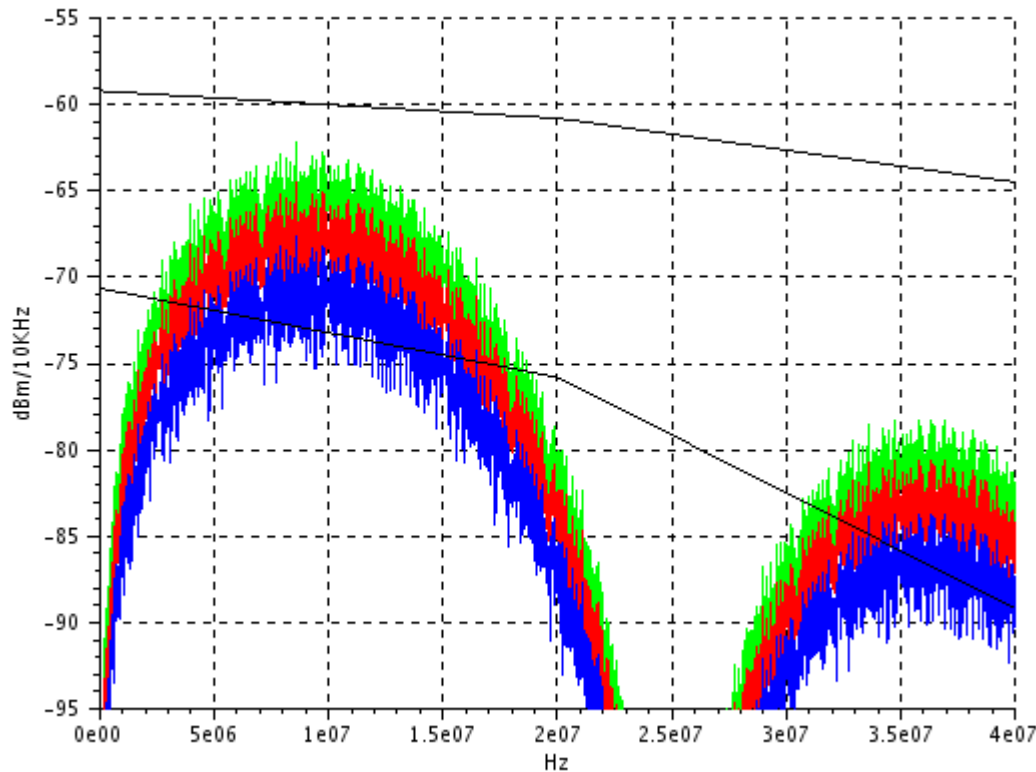
$$\text{Upper PSD}(f) = \begin{cases} -59.3 - 1.5 * \frac{f - 1}{19} & 300\text{KHz} < f < 20 \text{ MHz} \\ -60.8 - 3.7 * \frac{f - 20}{20} & 20 \text{ MHz} < f < 40 \text{ MHz} \\ -64.5 - 8.0 * \frac{f - 40}{17} & f > 40 \text{ MHz} \end{cases}$$

$$\text{Lower PSD}(f) = \begin{cases} -70.9 - 4.9 * \frac{f - 1}{19} & 300\text{KHz} < f < 20 \text{ MHz} \\ -75.8 - 13.4 * \frac{f - 20}{20} & f > 20 \text{ MHz} \end{cases}$$

# Proposal for PSD mask

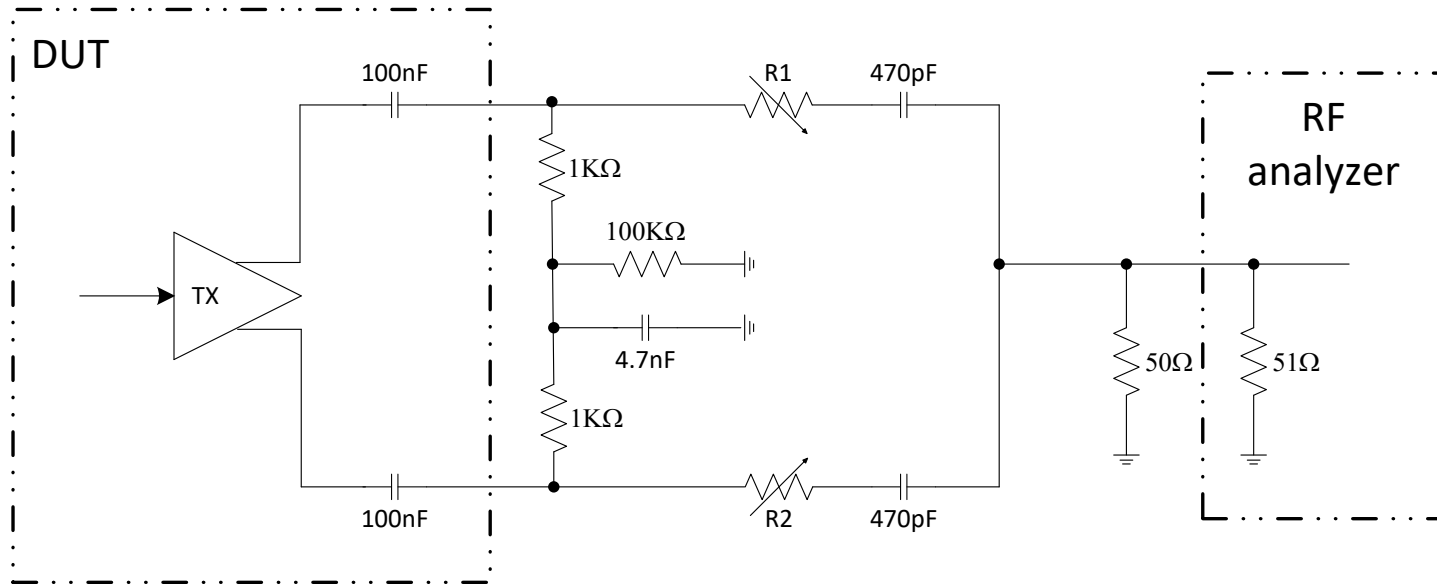


# Proposal for PSD mask



- Red: typ 1Vpp TX amplitude
- Green: +30% TX amplitude
- Blue: -30% TX amplitude

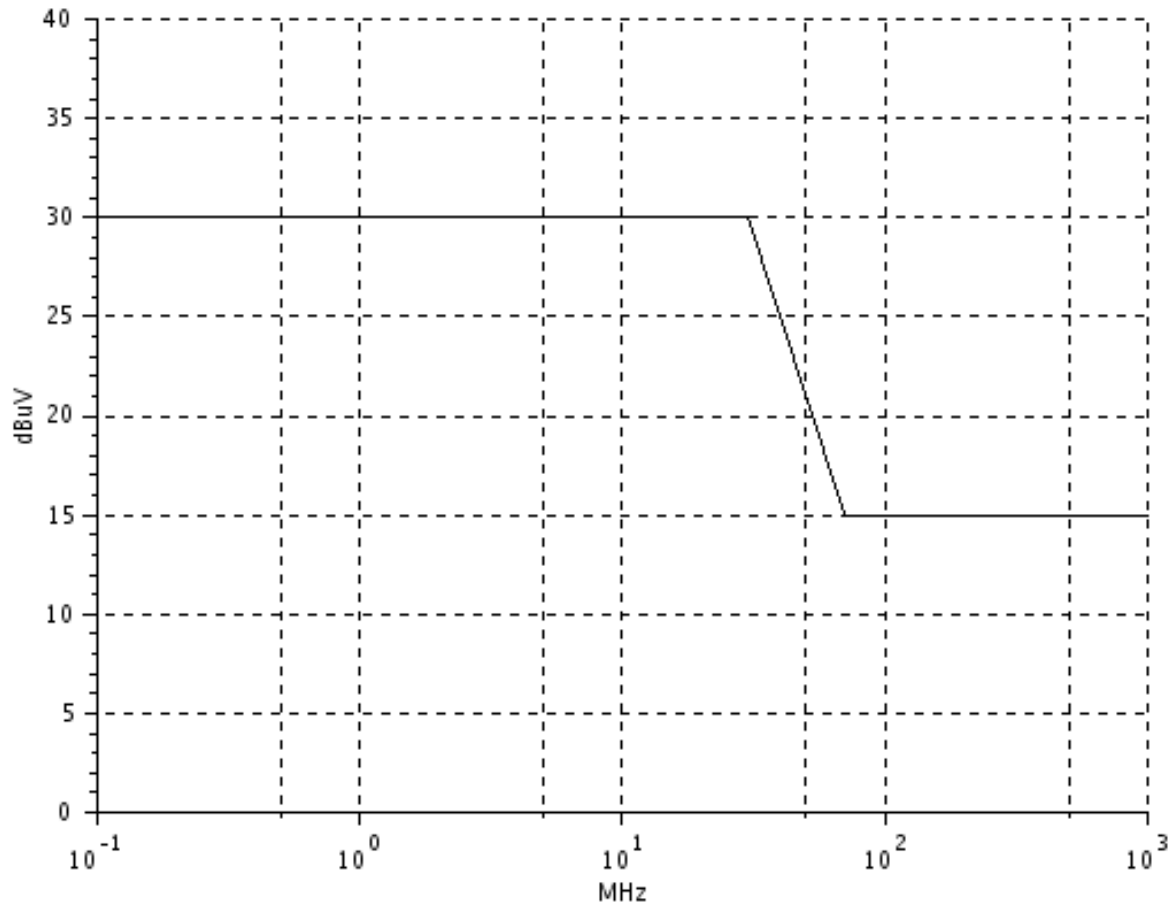
# Simulations: EMI tests



- **Direct Power Injection (DPI) and 150 Ohm emission tests for noise immunity and emission may be used to establish a baseline for PHY EMC performance**

Parameter coupling	R1 [ $\Omega$ ] (MDI P)	R2 [ $\Omega$ ] (MDI N)
Symmetry	120	120
+ 2.5 % unbalance	121	118
- 2.5 % unbalance	118	121
+ 5.0 % unbalance	121	115
- 5.0 % unbalance	115	121

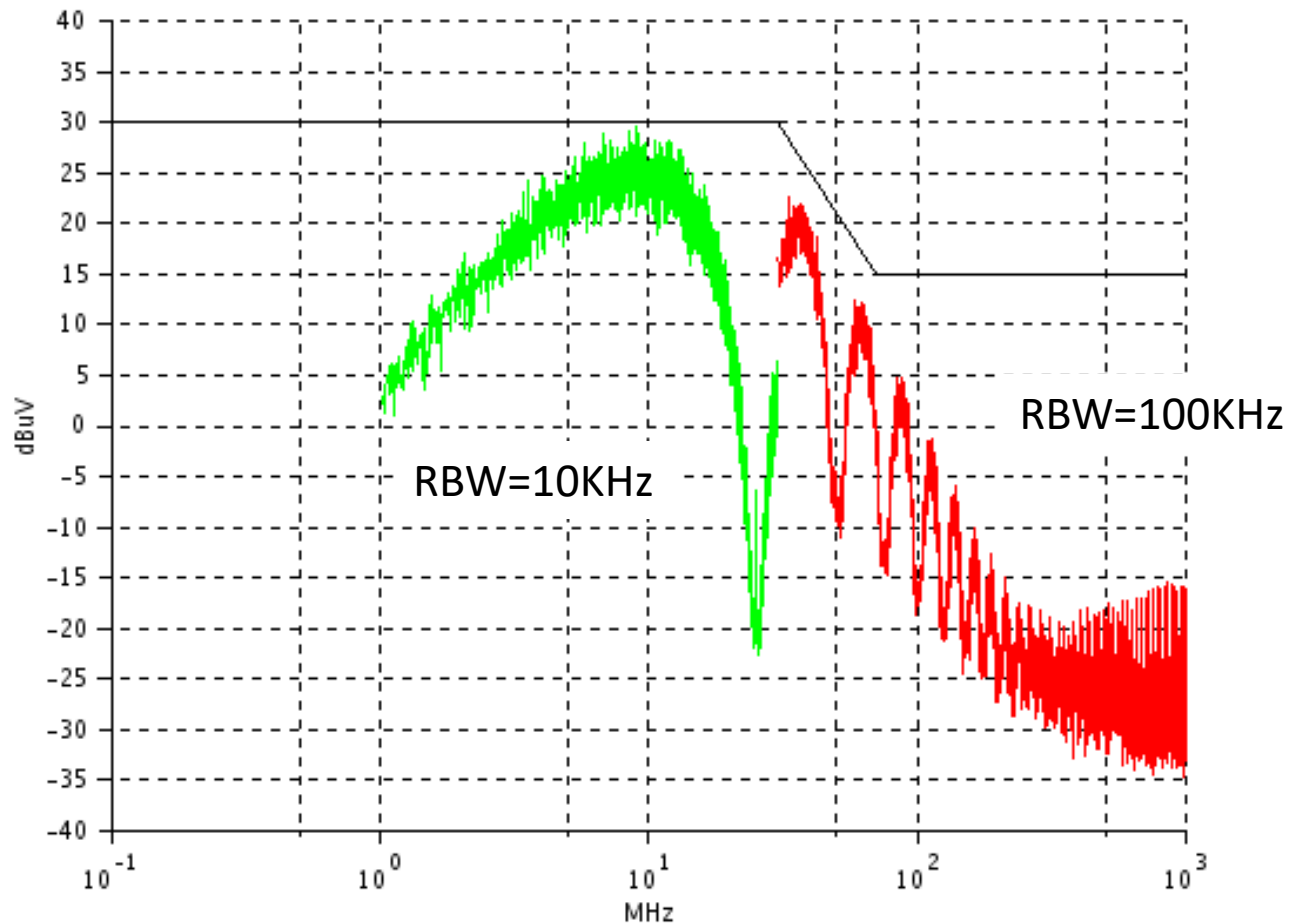
# EMI Requirements



$f < 30\text{MHz} \Rightarrow 30\text{dBuV}$

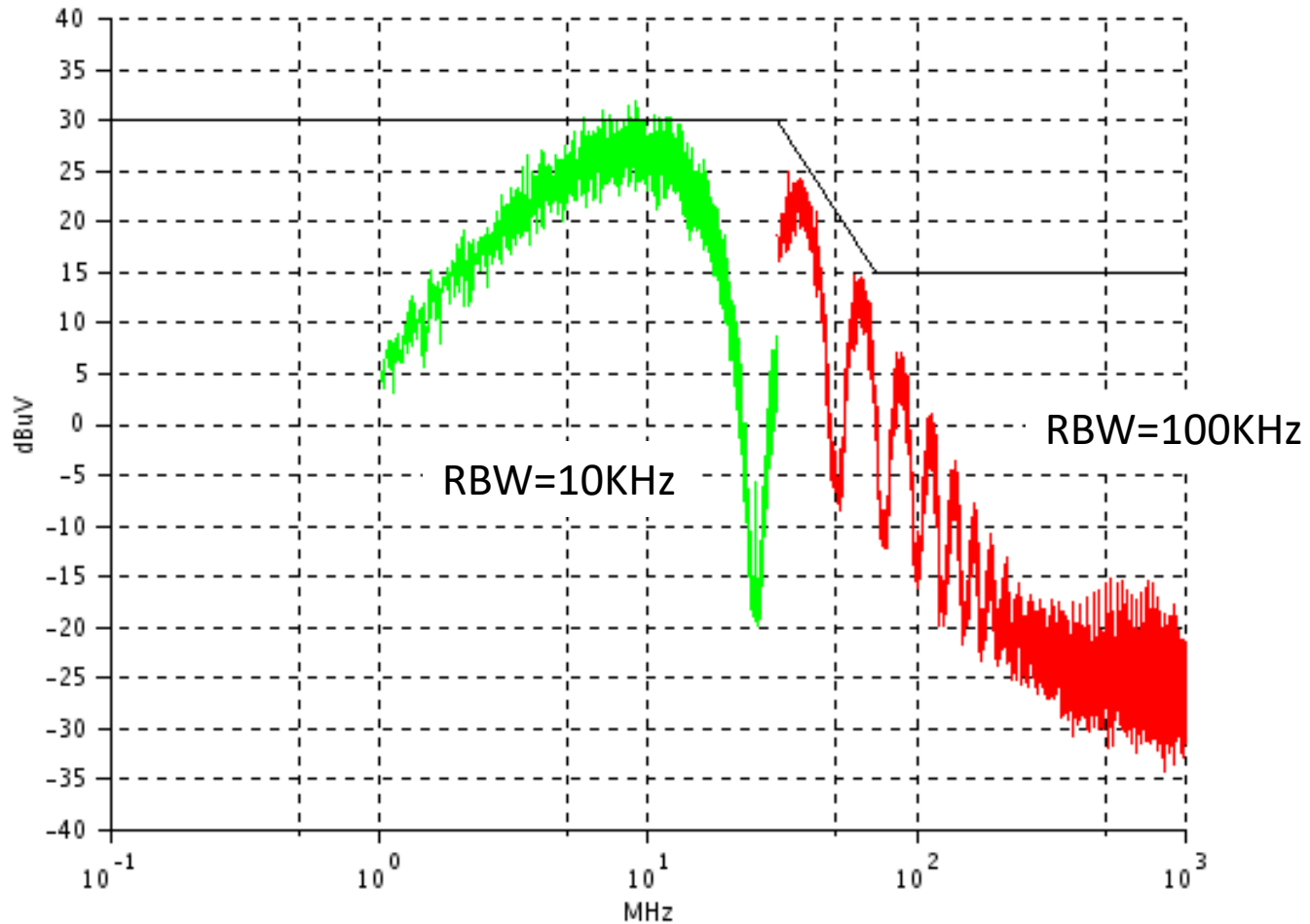
$f > 70\text{MHz} \Rightarrow 15\text{dBuV}$

# EMI Simulation $\pm 5\%$ unbalance, TX = 1 Vpp

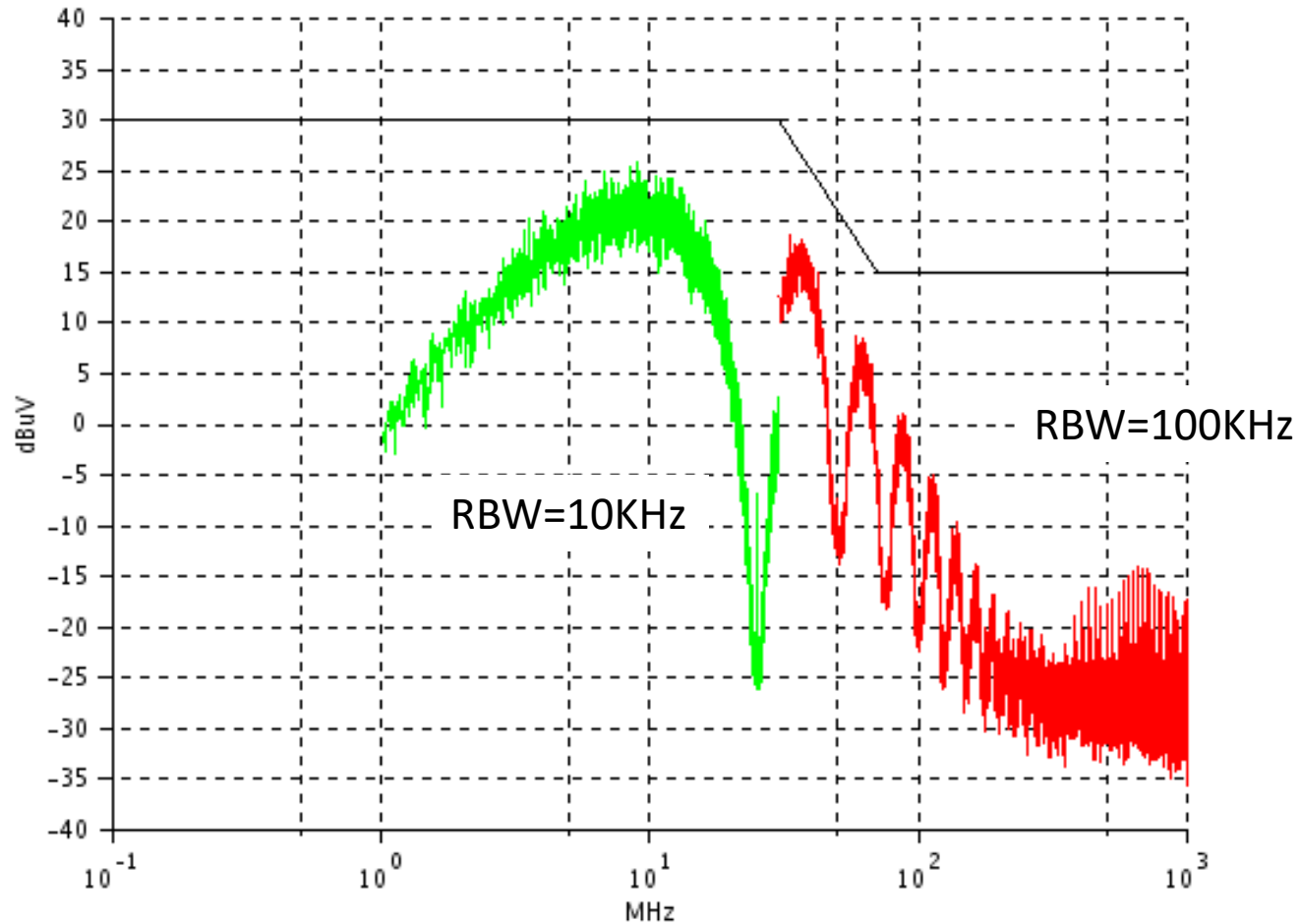




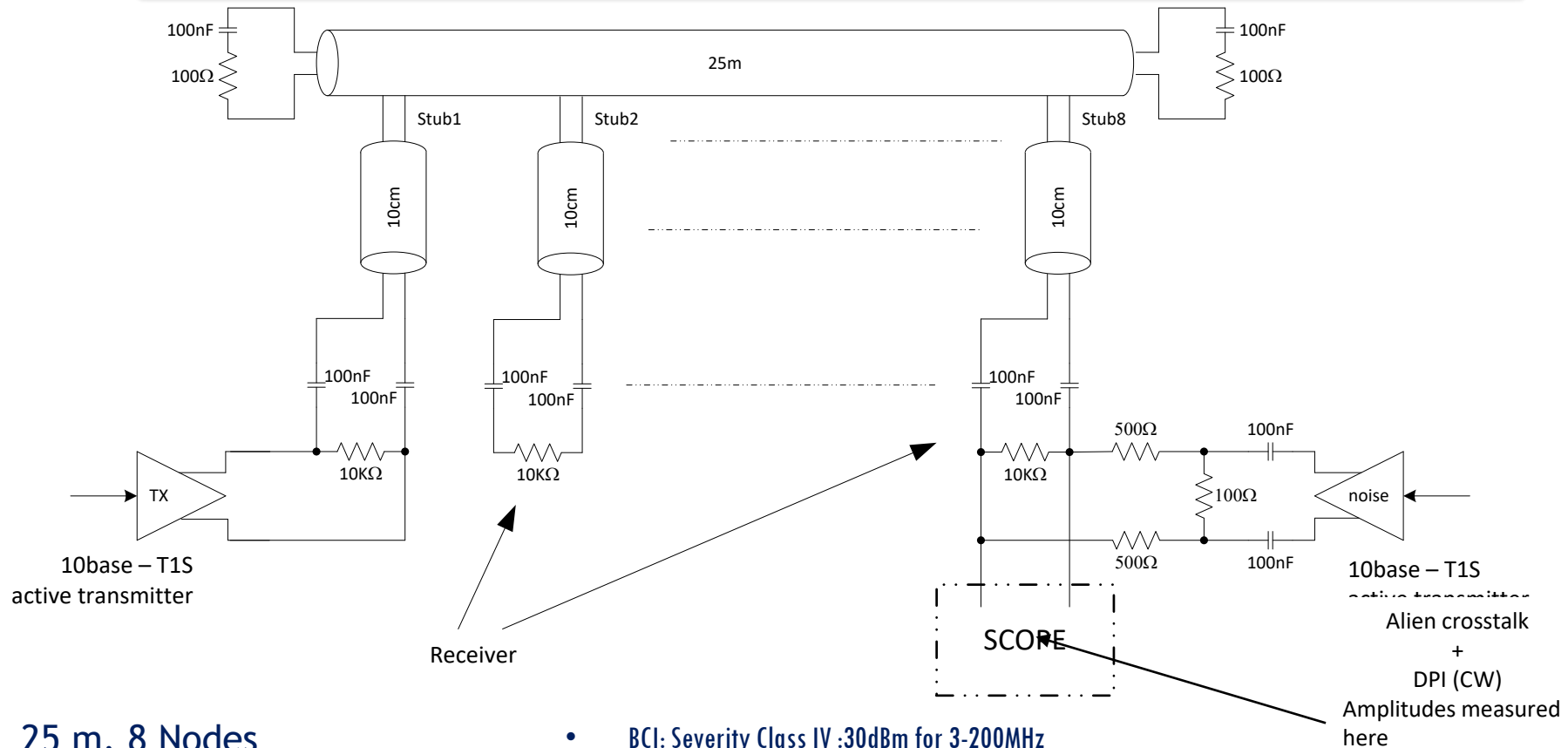
# EMI Simulation $\pm 5\%$ unbalance, TX = 1.3 Vpp



# EMI Simulation $\pm 2.5\%$ unbalance, TX = 1.3 Vpp



# Simulations: Multidrop mixing segment Test Bench

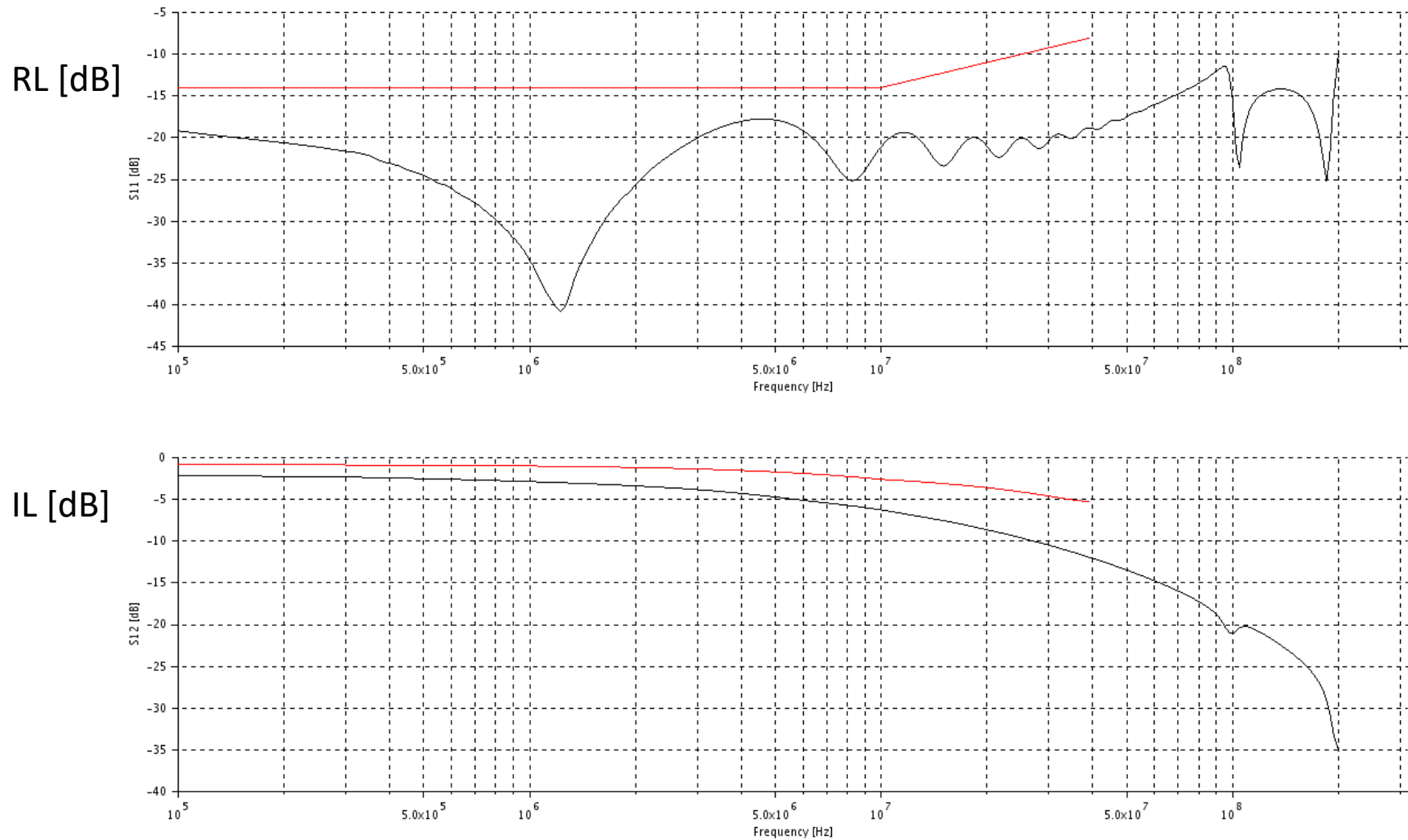


- 25 m, 8 Nodes
- $100\Omega \pm 1\%$  line termination resistance
- $50\Omega \pm 20\%$  transmitters (high-Z when silent)
- MC 43dB, 36.5dB and 30dB (comparison)

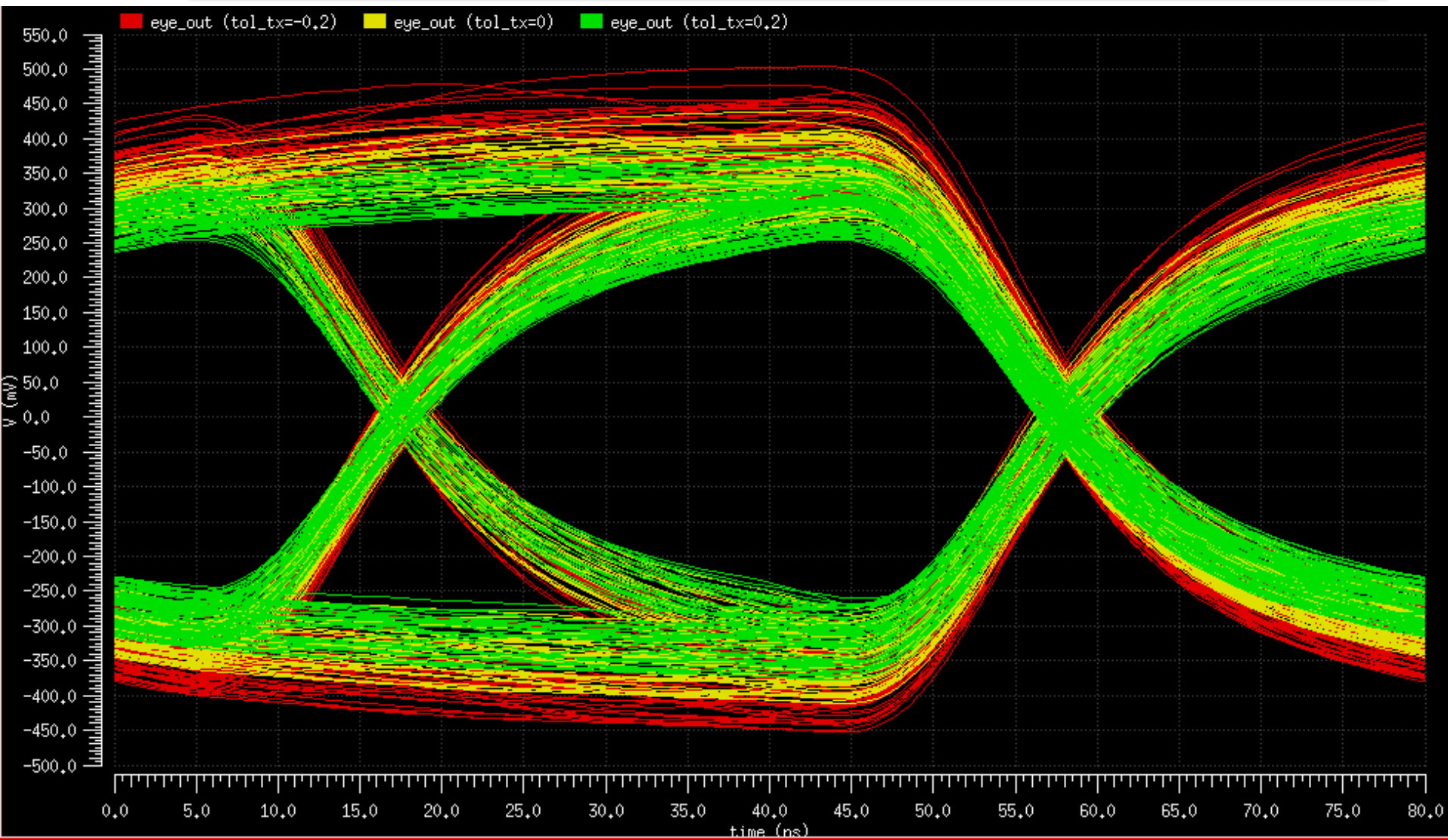
- BCI: Severity Class IV :30dBm for 3-200MHz
- 50mVpp Alien noise considered
- MC = 43 dB
  - BCI injected noise = 140mVpp
  - BCI + Alien noise = 190mVpp
- MC = 40 dB
  - BCI injected noise = 200mVpp
  - BCI + Alien noise = 250mVpp

- MC = 36.5 dB
  - BCI injected noise = 300mVpp
  - BCI + Alien noise = 350mVpp
- MC = 30 dB
  - BCI injected noise = 630mVpp
  - BCI + Alien noise = 680mVpp

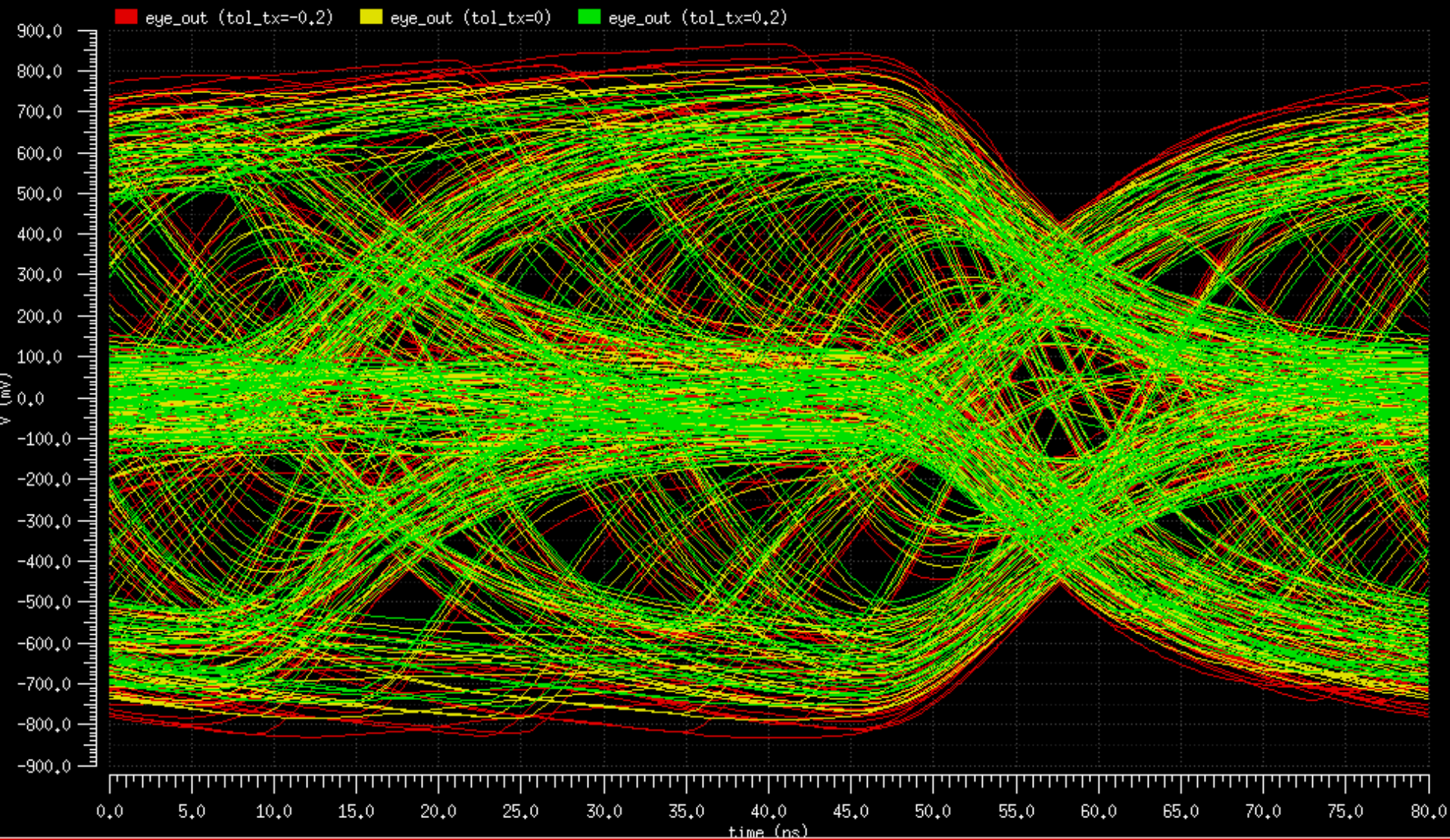
# Simulations: mixing segment RL, IL



## Mixing segment with 50mVpp Alien Noise

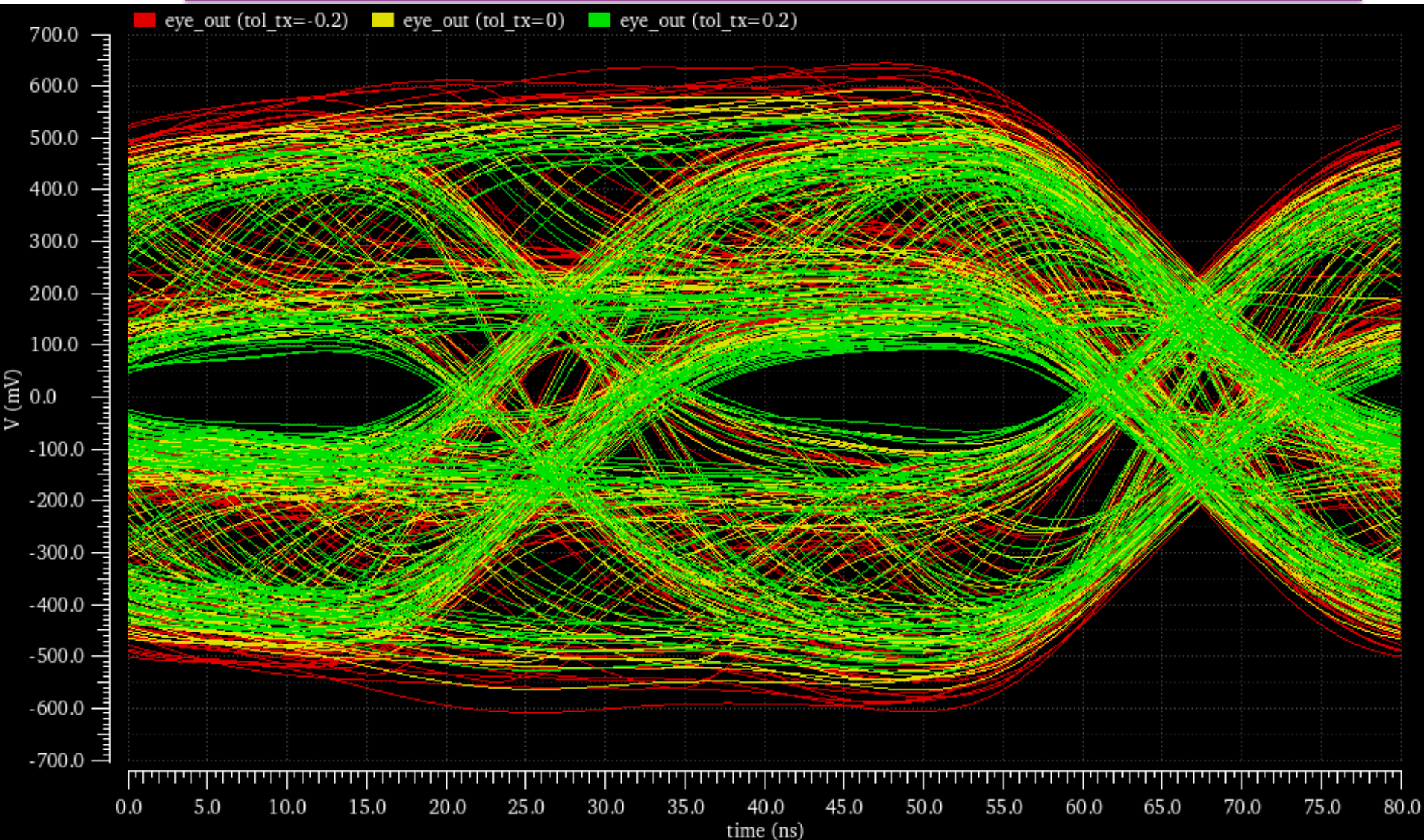


## Mixing segment with 50mVpp Alien Noise + DPI (30dbm) and MC = 30dB (total = 680mVpp)

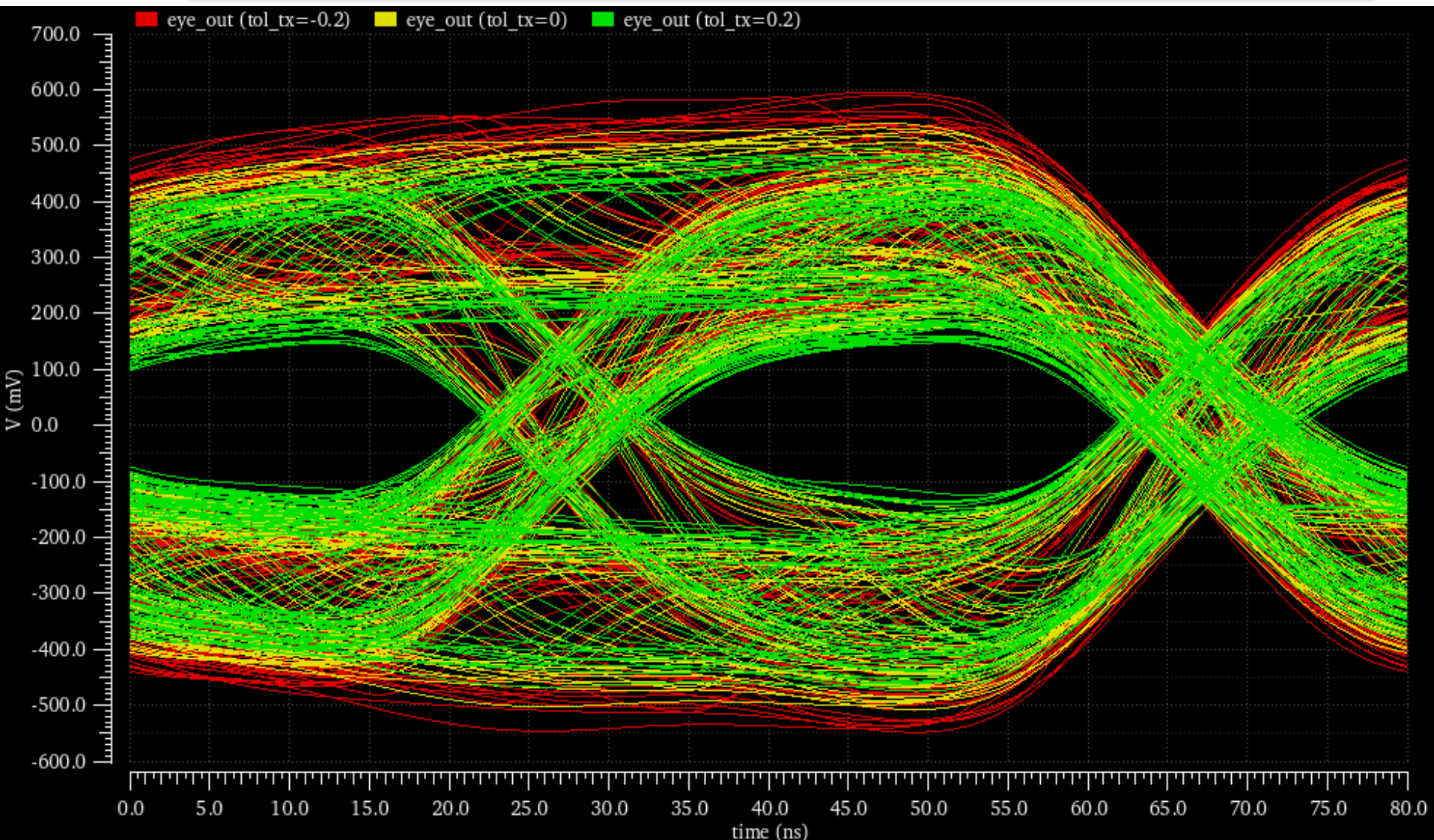




## Mixing segment with 50mVpp Alien Noise + DPI (30dbm) and MC = 36.5dB (total = 350mVpp)

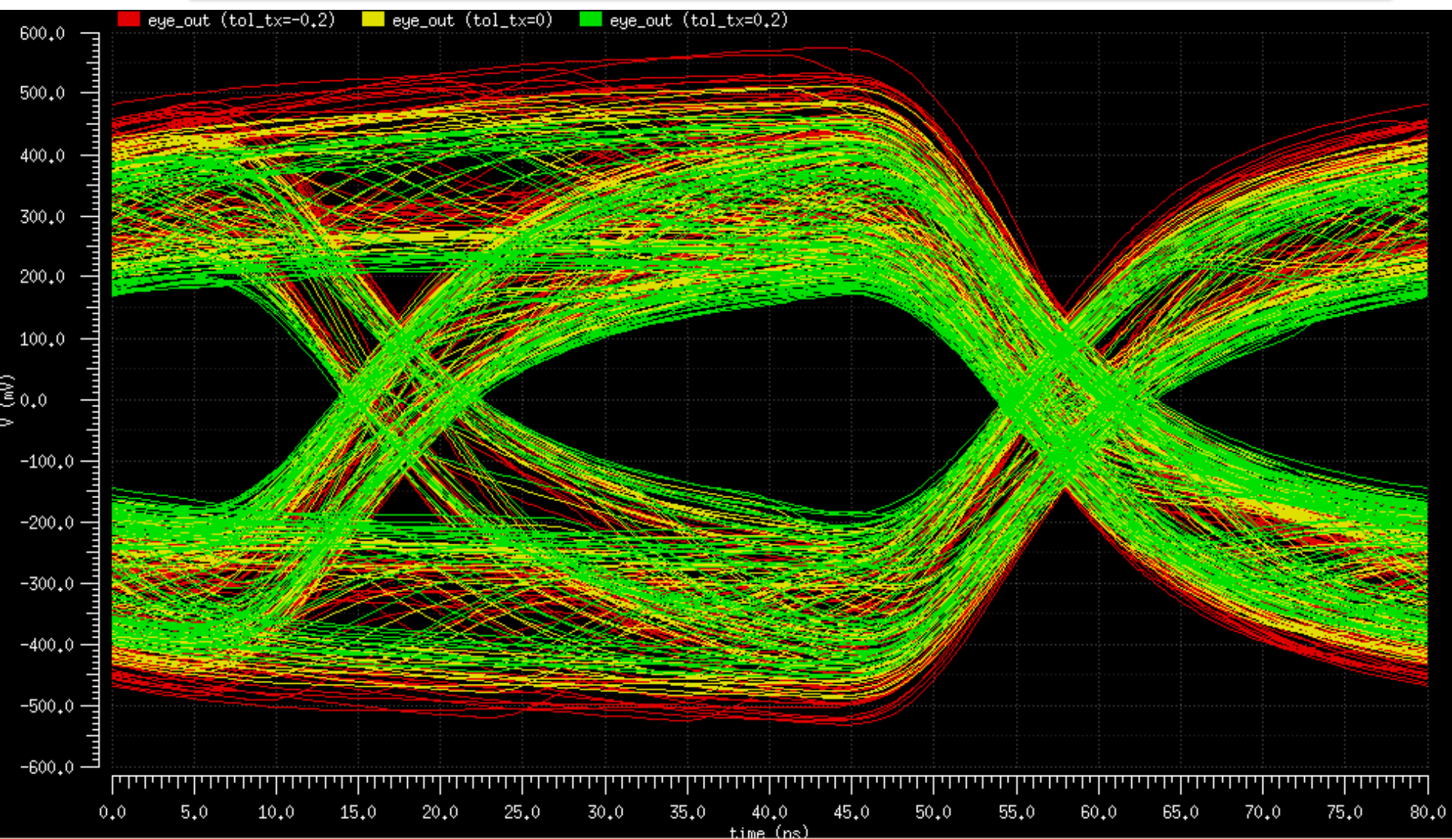


## Mixing segment with 50mVpp Alien Noise + DPI (30dbm) and MC = 40dB (total = 250mVpp)

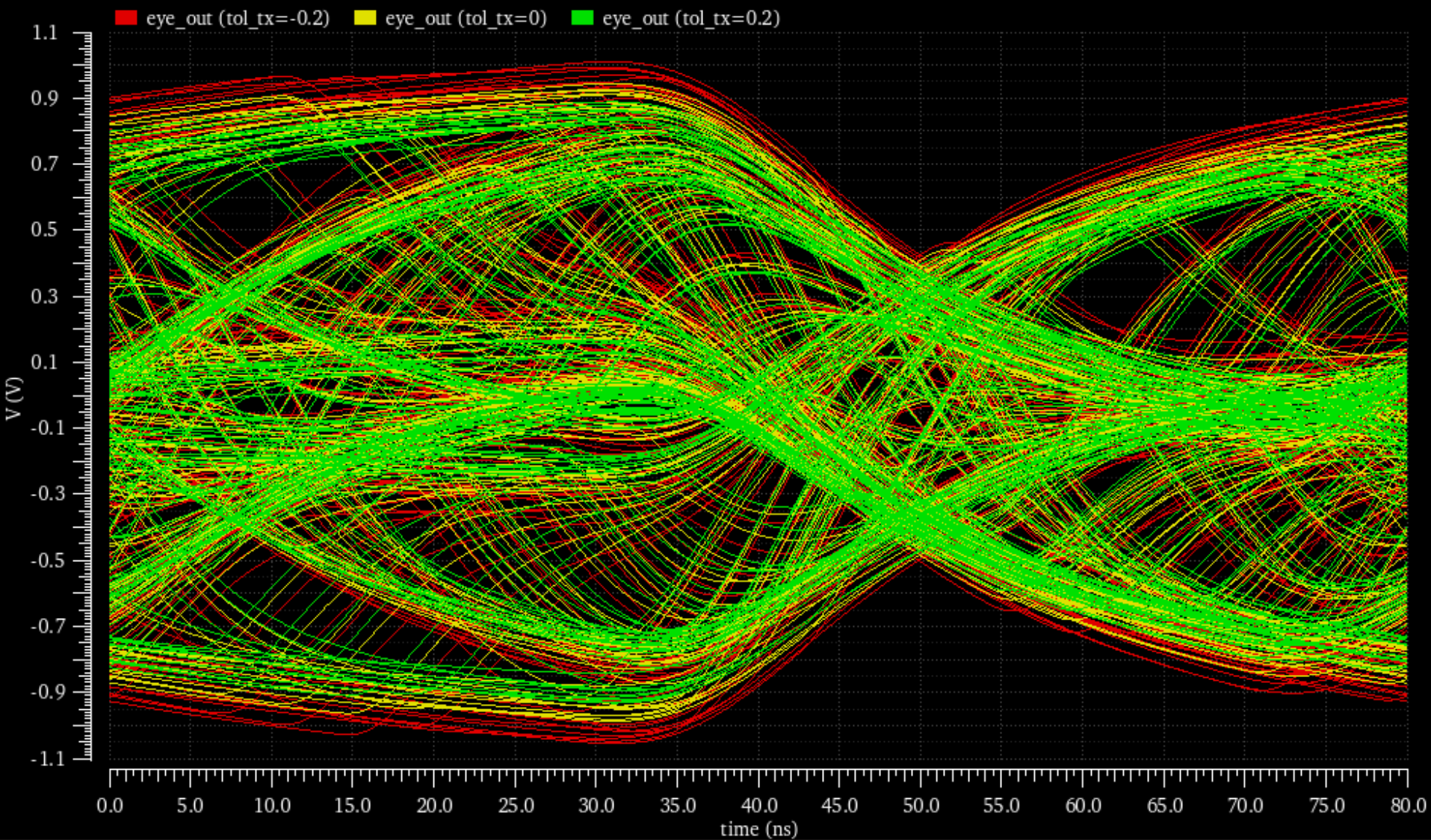




## Mixing segment with 50mVpp Alien Noise + DPI (30dbm) and MC = 43dB (total = 190mVpp)



# Mixing segment with 2Vpp TX + 100mVpp Alien Noise + DPI (30dbm) and MC = 30dB



- 30dB MC seems unreasonable
  - Increasing TX amplitude by 2x is not a solution
    - EMI likely out of specs anyway
- 36.5dB MC seems better but yields poor margin
- 40dB MC seems feasible
- 43dB (as in 802.3bw) looks safe
- Proposed change for TIS link segment / mixing segment definition